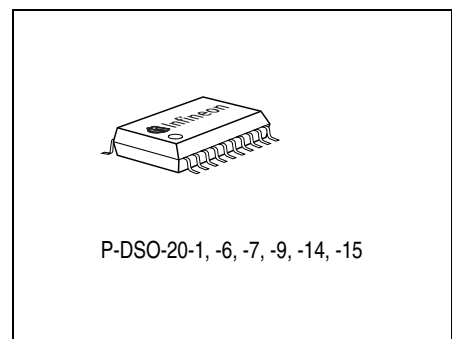
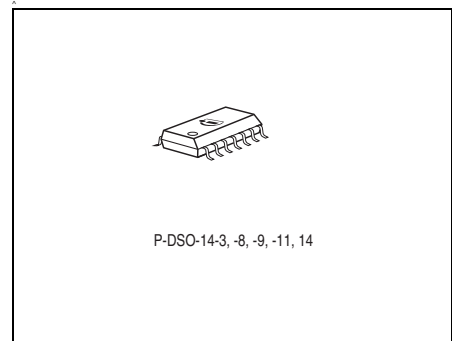
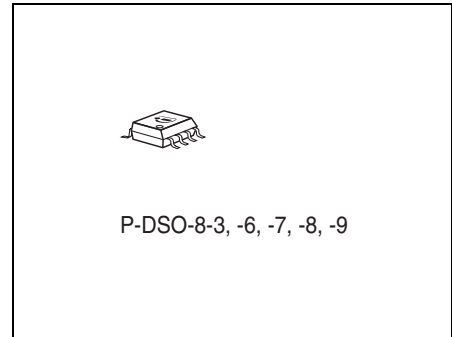


## Features

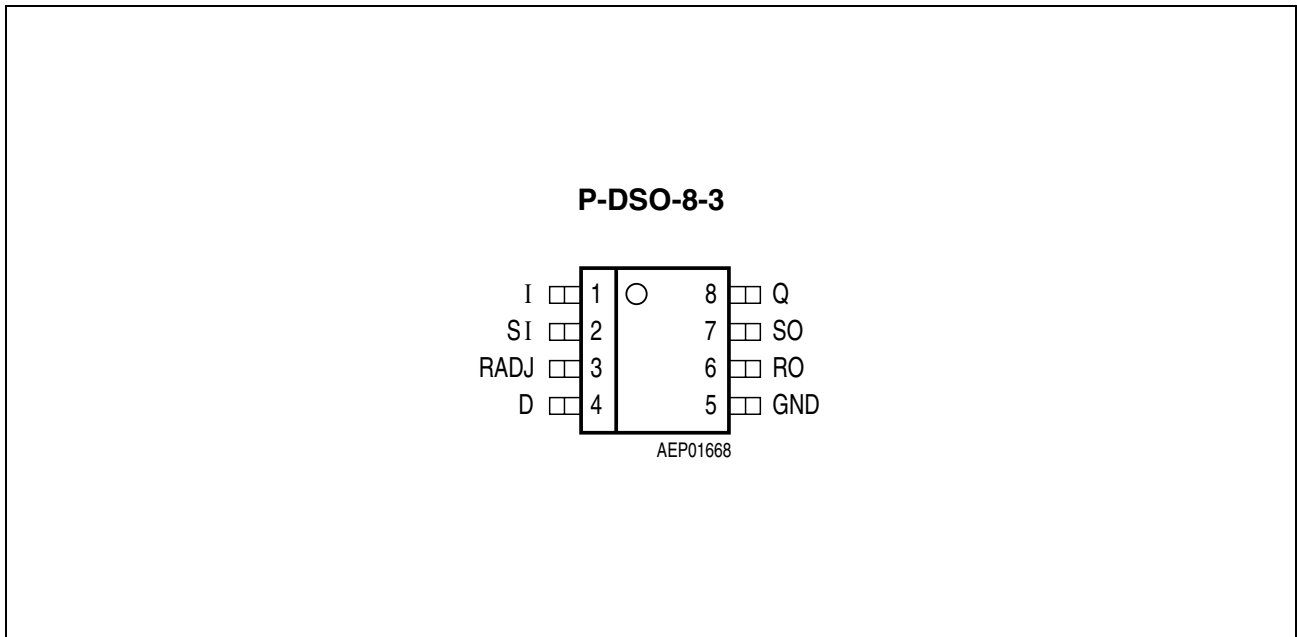
- Output voltage tolerance  $\leq \pm 2\%$
- 150 mA current capability
- Very low current consumption
- Early warning
- Reset output low down to  $V_Q = 1\text{ V}$
- Overtemperature protection
- Reverse polarity proof
- Adjustable reset threshold
- Very low drop voltage
- Wide temperature range
- Integrated pull-up resistor at logic outputs

## Functional Description

This device is an automotive suited voltage regulator with a fixed 5-V output. The maximum operating voltage is 45 V. The output is able to drive 150 mA load. It is short circuit protected and the thermal shutdown switches the output off if the junction temperature is in excess of 150 °C. A reset signal is generated for an output voltage of  $V_Q < 4.65\text{ V}$ . The reset threshold voltage can be decreased by external connection of a voltage divider. The reset delay time can be set by an external capacitor. Reset and sense output have integrated pull-up resistors. If the integrated resistors are not desired **TLE 4279** can be used. It is also possible to supervise the input voltage by using an integrated comparator to give a low voltage warning.



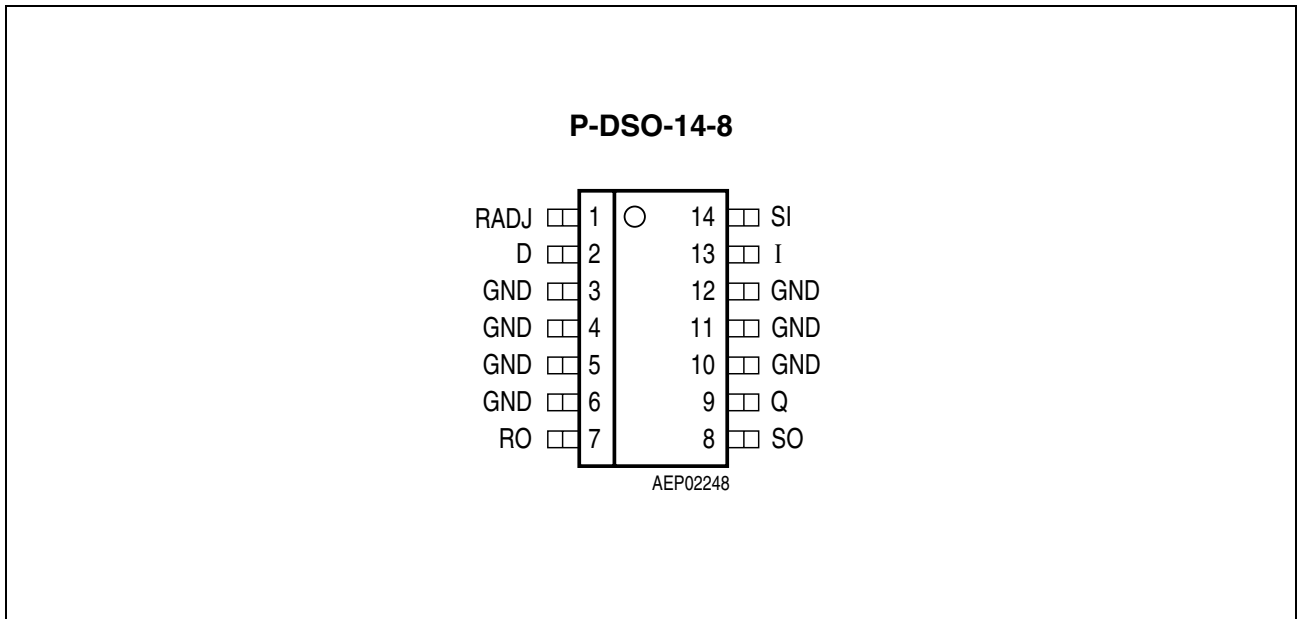
Type	Ordering Code	Package
TLE 4269 G	Q67006-A9173-A201K5	P-DSO-8-3
TLE 4269 GM	Q67006-A9288-A201K5	P-DSO-14-8
TLE 4269 GL	Q67006-A9192-C703	P-DSO-20-17



**Figure 1** Pin Configuration (top view)

**Table 1** Pin Definitions and Functions (TLE 4269 G)

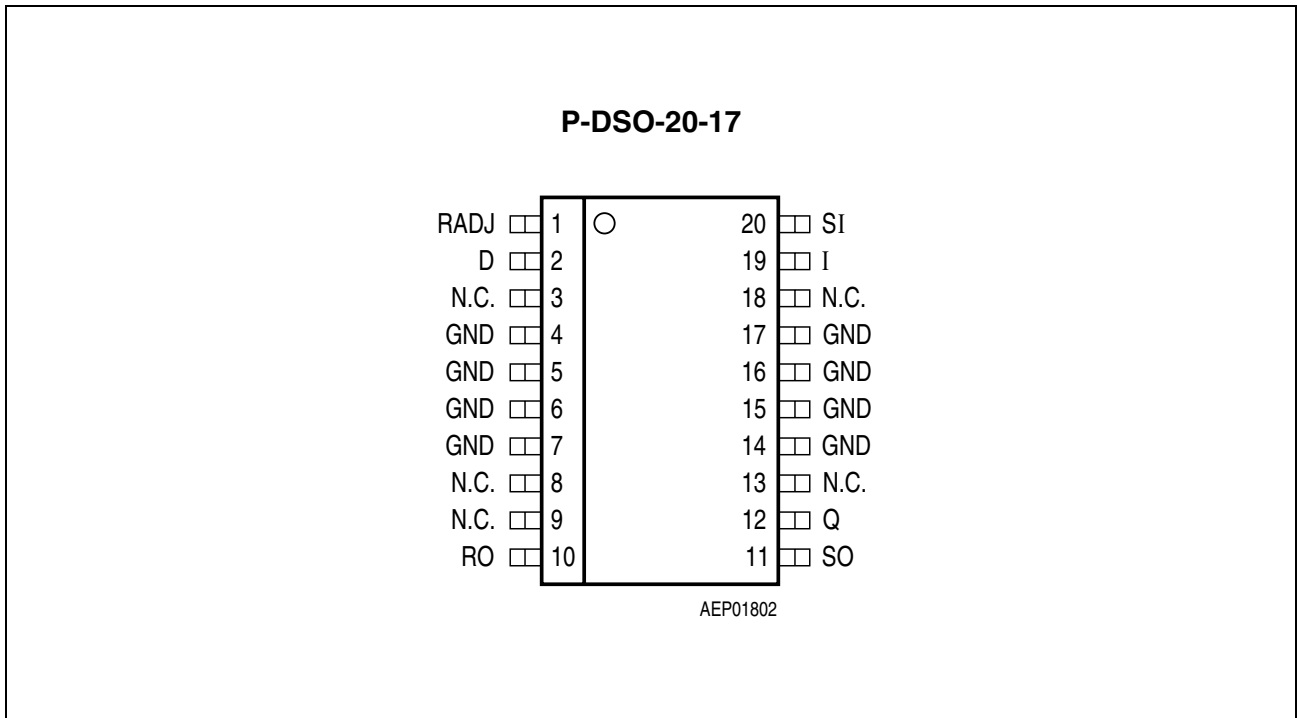
Pin No.	Symbol	Function
1	I	<b>Input;</b> block to GND directly at the IC with a ceramic capacitor.
2	SI	<b>Sense Input;</b> if not needed connect to Q.
3	RADJ	<b>Reset Threshold Adjust;</b> if not needed connect to GND.
4	D	<b>Reset Delay;</b> to select delay time, connect to GND via capacitor.
5	GND	<b>Ground</b>
6	RO	<b>Reset Output;</b> the open-collector output is internally linked to Q via a 20 kΩ pull-up resistor. Keep open, if not needed.
7	SO	<b>Sense Output;</b> the open-collector output is internally linked to the output via a 20 kΩ pull-up resistor. Keep open, if not needed.
8	Q	<b>5-V Output;</b> connect to GND with a 10 μF capacitor, ESR < 10 Ω.



**Figure 2 Pin Configuration (top view)**

**Table 2 Pin Definitions and Functions (TLE 4269 GM)**

Pin No.	Symbol	Function
1	RADJ	<b>Reset Threshold Adjust</b> ; if not needed connect to GND.
2	D	<b>Reset Delay</b> ; to select delay time; connect to GND via capacitor.
3, 4, 5, 6	GND	<b>Ground</b>
7	RO	<b>Reset Output</b> ; open-collector output, internally connected to Q via a pull-up resistor of 20 kΩ. Keep open, if not needed.
8	SO	<b>Sense Output</b> ; open-collector output, internally connected to Q via a 20 kΩ pull-up resistor. Keep open, if not needed.
9	Q	<b>5-V Output</b> ; connect to GND with a 10 μF capacitor, ESR < 10 Ω.
10, 11, 12	GND	<b>Ground</b>
13	I	<b>Input</b> ; block to GND directly at the IC with a ceramic capacitor.
14	SI	<b>Sense Input</b> ; if not needed connect to Q.



**Figure 3 Pin Configuration (top view)**

**Table 3 Pin Definitions and Functions (TLE 4269 GL)**

Pin No.	Symbol	Function
1	RADJ	<b>Reset Threshold Adjust</b> ; if not needed connect to ground.
2	D	<b>Reset Delay</b> ; to select delay time, connect to GND via external capacitor.
4 - 7, 14 - 17	GND	<b>Ground</b>
10	RO	<b>Reset Output</b> ; the open-collector output is internally linked to Q via a 20 kΩ pull-up resistor. Keep open, if not needed.
11	SO	<b>Sense Output</b> ; the open-collector output is internally linked to the output via a 20 kΩ pull-up resistor. Keep open, if not needed.
12	Q	<b>Output</b> ; connect to GND with a 10 μF capacitor, ESR < 10 Ω.
19	I	<b>Input</b> ; block directly at the IC by a ceramic capacitor.
20	SI	<b>Sense Input</b> ; if not needed connect to Q.

## Circuit Description

The control amplifier compares a reference voltage, made highly accurate by resistance balancing, with a voltage proportional to the output voltage and drives the base of the series PNP transistor via a buffer. Saturation control as a function of the load current prevents any over-saturation of the power element.

The reset output RO is in high-state if the voltage on the delay capacitor  $C_D$  is greater or equal  $V_{UD}$ . The delay capacitor  $C_D$  is charged with the current  $I_D$  for output voltages greater than the reset threshold  $V_{RT}$ . If the output voltage gets lower than  $V_{RT}$  ('reset condition') a fast discharge of the delay capacitor  $C_D$  sets in and as soon as  $V_D$  gets lower than  $V_{LD}$  the reset output RO is set to low-level.

The time gap for the delay capacitor discharge is the reset reaction time  $t_{RR}$ .

The reset threshold  $V_{RT}$  can be decreased via an external voltage divider connected to the pin RADJ. In this case the reset condition is reached if  $V_Q < V_{RT}$  and  $V_{RADJ} < V_{RAQDJ, TH}$ . Dimensioning the voltage divider (**Figure 5**) according to:

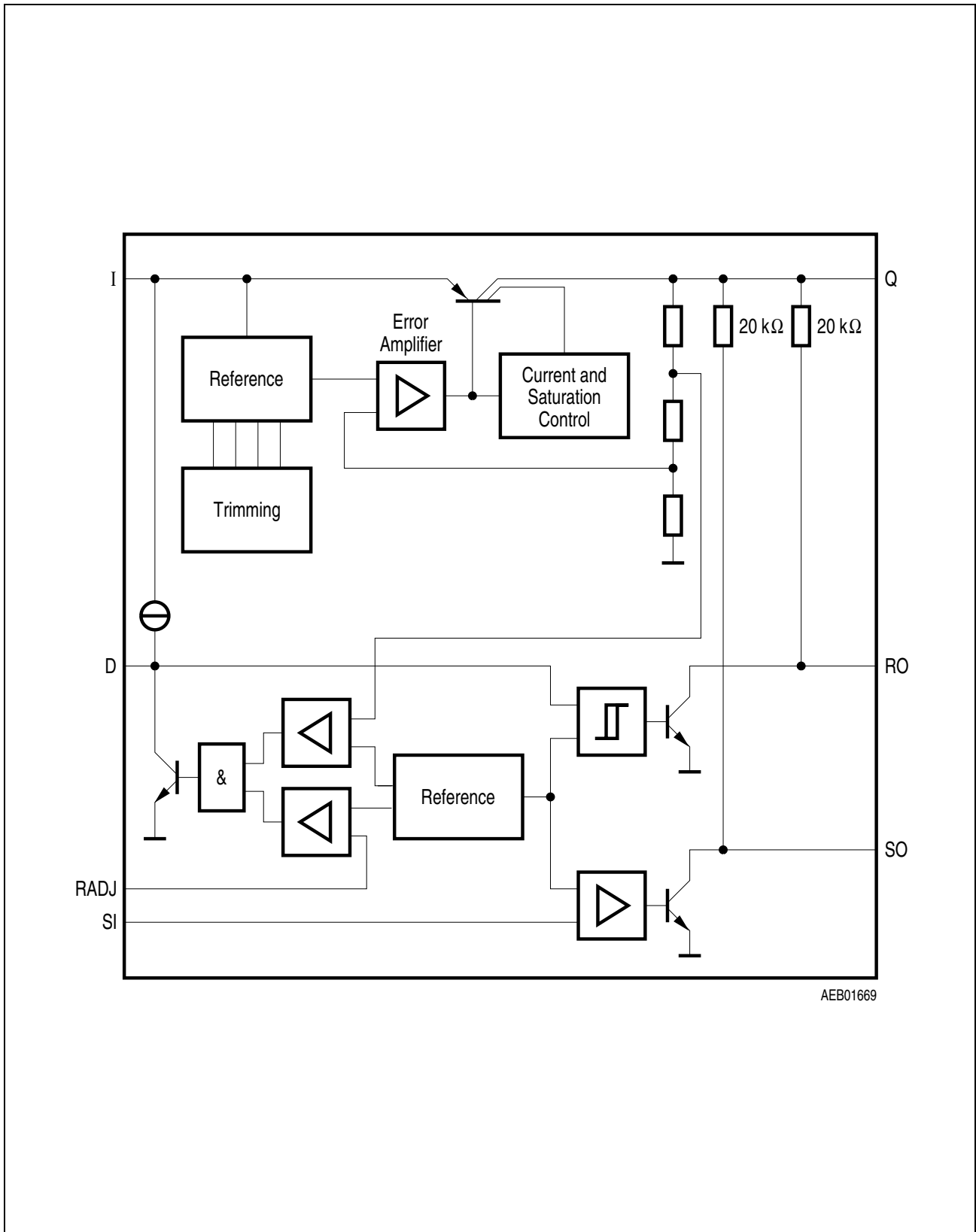
$$V_{THRES} = V_{RADJ, TH} \times (R_{ADJ1} + R_{ADJ2}) / R_{ADJ2}, \quad (1)$$

the reset threshold can be decreased down to 3.5 V. If the reset-adjust-option is not needed the RADJ-pin should be connected to GND causing the reset threshold to go to its default value (typ. 4.65 V).

A built in comparator compares the signal of the pin SI, normally fed by a voltage divider from the input voltage, with the reference and gives an early warning on the pin SO. It is also possible to supervise another voltage e.g. of a second regulator, or to build a watchdog circuit with few external components.

## Application Description

The input capacitor  $C_I$  is necessary for compensating line influences. Using a resistor of approx. 1  $\Omega$  in series with  $C_I$ , the oscillating circuit consisting of input inductivity and input capacitance can be damped. The output capacitor  $C_Q$  is necessary for the stability of the regulating circuit. Stability is guaranteed at values  $\geq 10 \mu\text{F}$  and an ESR  $\leq 10 \Omega$  within the operating temperature range. For small tolerances of the reset delay the spread of the capacitance of the delay capacitor and its temperature coefficient should be noted.



**Figure 4** Block Diagram

**Table 4 Absolute Maximum Ratings**
 $T_j = -40$  to  $150$  °C

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
<b>Input</b>					
Input voltage	$V_I$	-40	45	V	–
Input current	$I_I$	–	–	–	internal limited
<b>Sense Input</b>					
Input voltage	$V_{SI}$	-40	45	V	–
Input current	$I_{SI}$	1	1	mA	–
<b>Reset Threshold</b>					
Voltage	$V_{RADJ}$	-0.3	7	V	–
Current	$I_{RADJ}$	-10	10	mA	–
<b>Reset Delay</b>					
Voltage	$V_D$	-0.3	7	V	–
Current	$I_D$	–	–	–	internal limited
<b>Ground</b>					
Current	$I_{GND}$	50	–	mA	–
<b>Reset Output</b>					
Voltage	$V_R$	-0.3	7	V	–
Current	$I_R$	–	–	–	internal limited
<b>Sense Output</b>					
Voltage	$V_{SO}$	-0.3	7	V	–
Current	$I_{SO}$	–	–	–	internal limited
<b>5-V Output</b>					
Output voltage	$V_Q$	-0.5	7	V	–
Output current	$I_Q$	-10	–	mA	–
<b>Temperature</b>					
Junction temperature	$T_j$	–	150	°C	–
Storage temperature	$T_{Stg}$	-50	150	°C	–

**Table 4 Absolute Maximum Ratings (cont'd)**
 $T_j = -40$  to  $150$  °C

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
<b>Operating Range</b>					
Input voltage	$V_I$	–	45	V	–
Junction temperature	$T_j$	-40	150	°C	–
<b>Thermal Data</b>					
Junction-ambient	$R_{thja}$	–	200	K/W	P-DSO-8-3
		–	70	K/W	P-DSO-14-8
		–	70	K/W	P-DSO-20-17
Junction-pin	$R_{thjp}$	–	30	K/W	P-DSO-14-8 <sup>1)</sup>
		–	30	K/W	P-DSO-20-17 <sup>1)</sup>

1) Measured to Pin 4

**Table 5 Characteristics**
 $V_I = 13.5$  V;  $T_j = -40$  °C <  $T_j$  <  $125$  °C

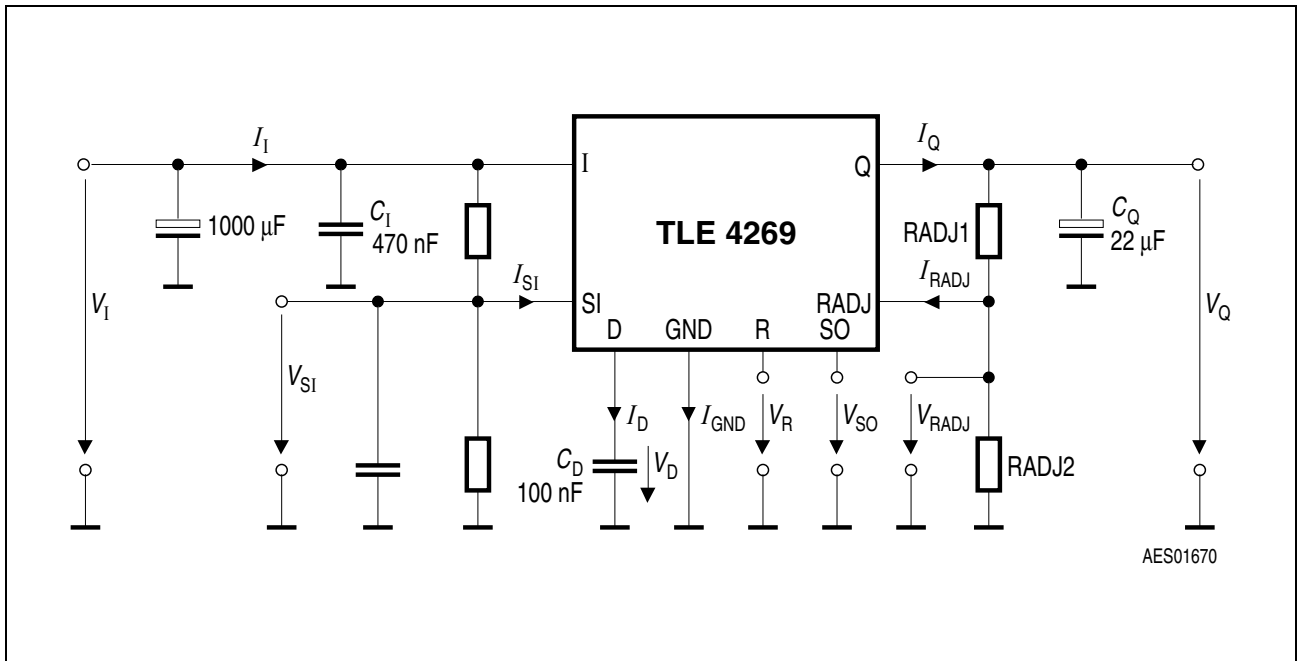
Parameter	Symbol	Limit Values			Unit	Measuring Condition
		Min.	Typ.	Max.		
Output voltage	$V_Q$	4.90	5.00	5.10	V	$1 \text{ mA} \leq I_Q \leq 100 \text{ mA}$ , $6 \text{ V} \leq V_I \leq 16 \text{ V}$
Current limit	$I_Q$	150	200	500	mA	–
Current consumption; $I_q = I_I - I_Q$	$I_q$	–	240	300	µA	$I_Q \leq 1 \text{ mA}$ , $T_j < 85$ °C
Current consumption; $I_q = I_I - I_Q$	$I_q$	–	250	700	µA	$I_Q = 10 \text{ mA}$
Current consumption; $I_q = I_I - I_Q$	$I_q$	–	2	8	mA	$I_Q = 50 \text{ mA}$
Drop voltage	$V_{dr}$	–	0.25	0.5	V	$I_Q = 100 \text{ mA}$ <sup>1)</sup>
Load regulation	$\Delta V_Q$	–	10	30	mV	$I_Q = 5 \text{ mA}$ to $100 \text{ mA}$
Line regulation	$\Delta V_Q$	–	10	40	mV	$V_I = 6 \text{ V}$ to $26 \text{ V}$ , $I_Q = 1 \text{ mA}$



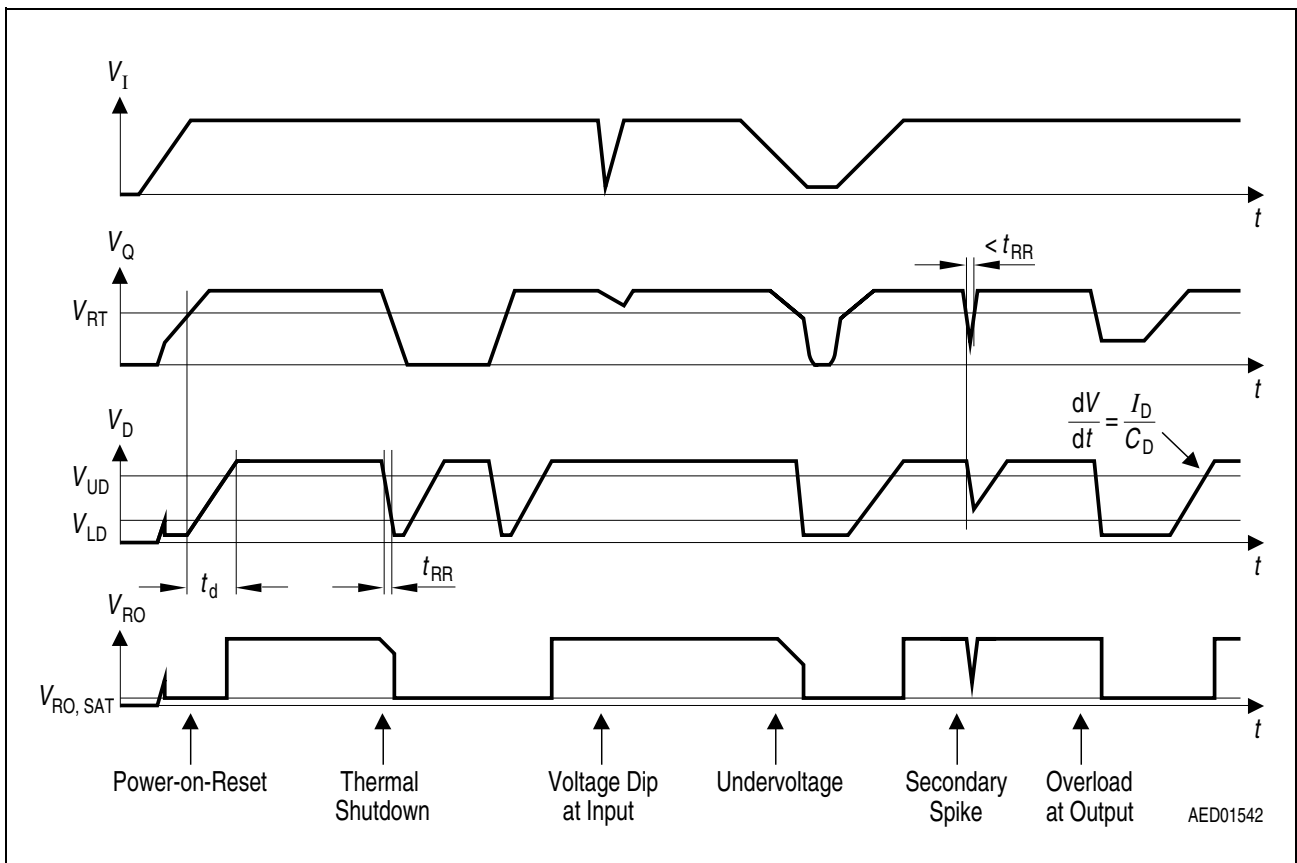
**Table 5 Characteristics (cont'd)**
 $V_I = 13.5 \text{ V}; T_j = -40 \text{ }^\circ\text{C} < T_j < 125 \text{ }^\circ\text{C}$ 

Parameter	Symbol	Limit Values			Unit	Measuring Condition
		Min.	Typ.	Max.		
<b>Reset Generator</b>						
Switching threshold	$V_{RT}$	4.50	4.65	4.80	V	–
Reset adjust switching threshold	$V_{RADJ, TH}$	1.26	1.35	1.44	V	$V_Q > 3.5 \text{ V}$
Reset pull-up	–	10	20	40	k $\Omega$	–
Saturation voltage	$V_{RO, SAT}$	–	0.1	0.4	V	$R_{intern}$
Upper delay switching threshold	$V_{UD}$	1.4	1.8	2.2	V	–
Lower delay switching threshold	$V_{LD}$	0.3	0.45	0.60	V	–
Saturation voltage delay capacitor	$V_{D, SAT}$	–	–	0.1	V	$V_Q < V_{RT}$
Charge current	$I_D$	3.0	6.5	9.5	$\mu\text{A}$	$V_D = 1 \text{ V}$
Delay time L $\rightarrow$ H	$t_d$	17	28	–	ms	$C_D = 100 \text{ nF}$
Delay time H $\rightarrow$ L	$t_t$	–	1	–	$\mu\text{s}$	$C_D = 100 \text{ nF}$
<b>Input Voltage Sense</b>						
Sense threshold high	$V_{SI, high}$	1.24	1.31	1.38	V	–
Sense threshold low	$V_{SI, low}$	1.16	1.20	1.28	V	–
Sense output low voltage	$V_{SO, low}$	–	0.1	0.4	V	$V_{SI} < 1.20 \text{ V}; V_Q > 3 \text{ V}, R_{intern}$
Sense pull-up	–	10	20	40	k $\Omega$	–
Sense input current	$I_{SI}$	-1	0.1	1	$\mu\text{A}$	–

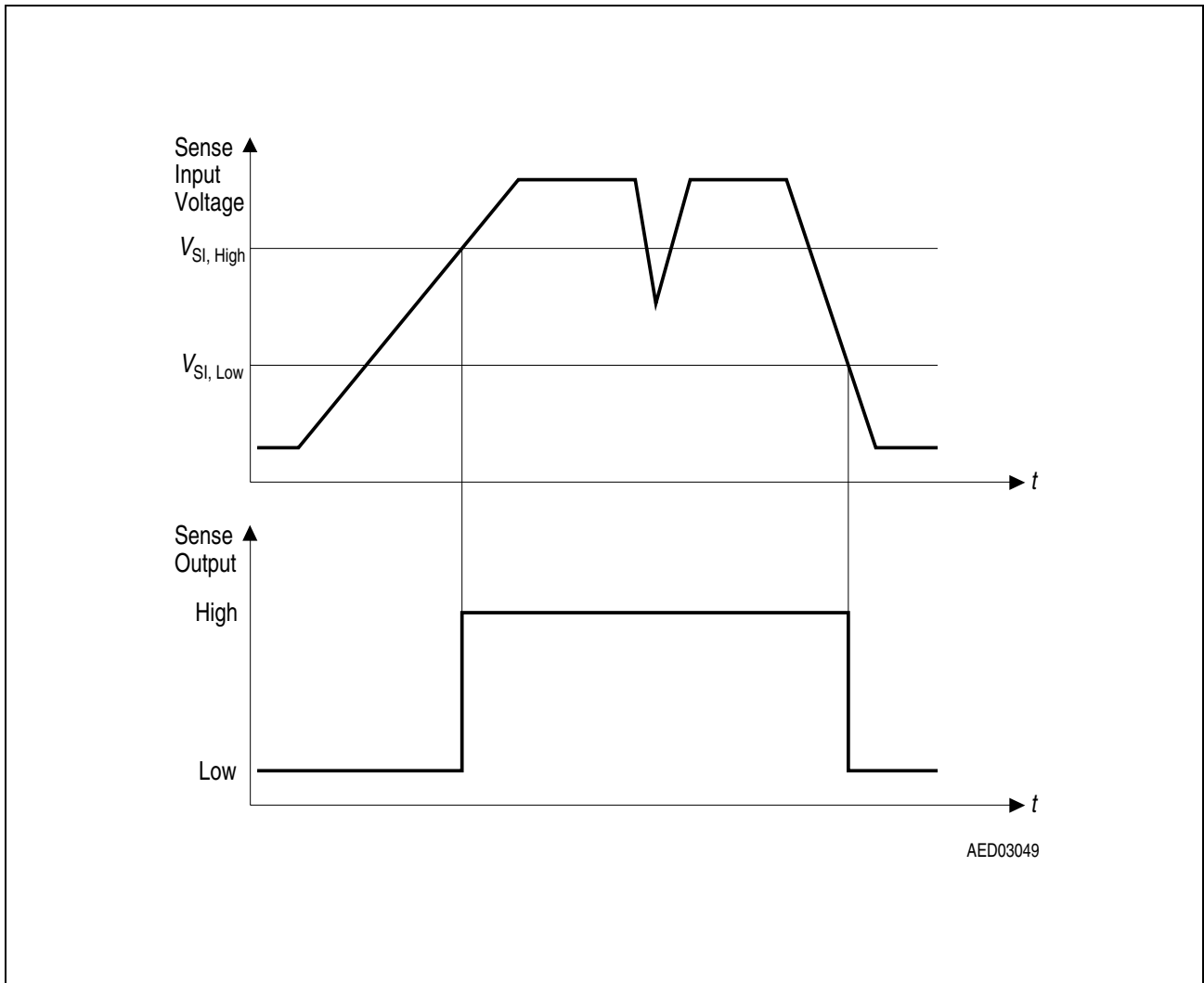
1) Drop voltage =  $V_I - V_Q$  measured when the output voltage has dropped 100 mV from the nominal value obtained at 13.5 V input.



**Figure 5 Measuring Circuit**

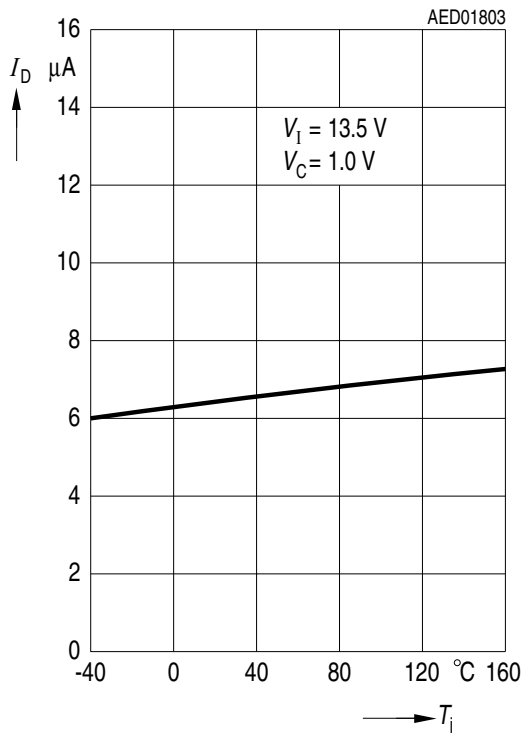


**Figure 6 Reset Timing Diagram**

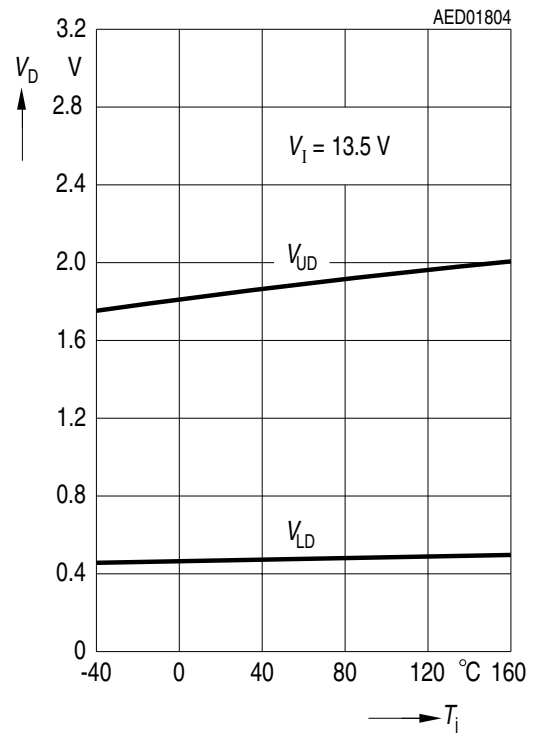


**Figure 7 Sense Timing Diagram**

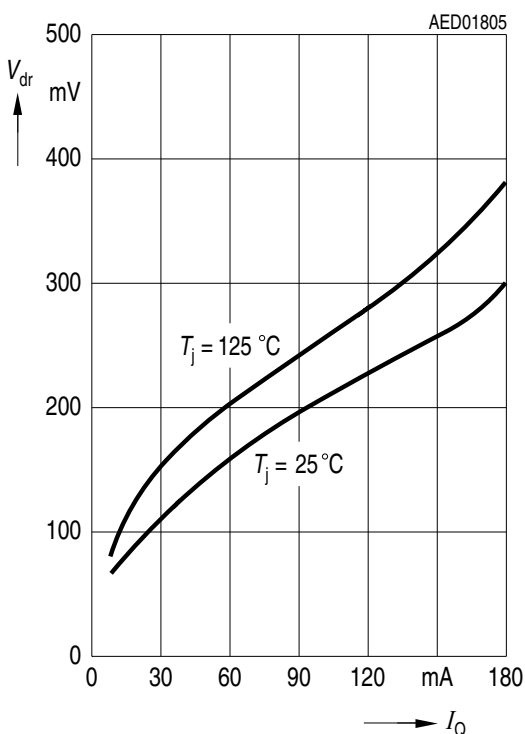
**Charge Current  $I_D$  versus Temperature  $T_i$**



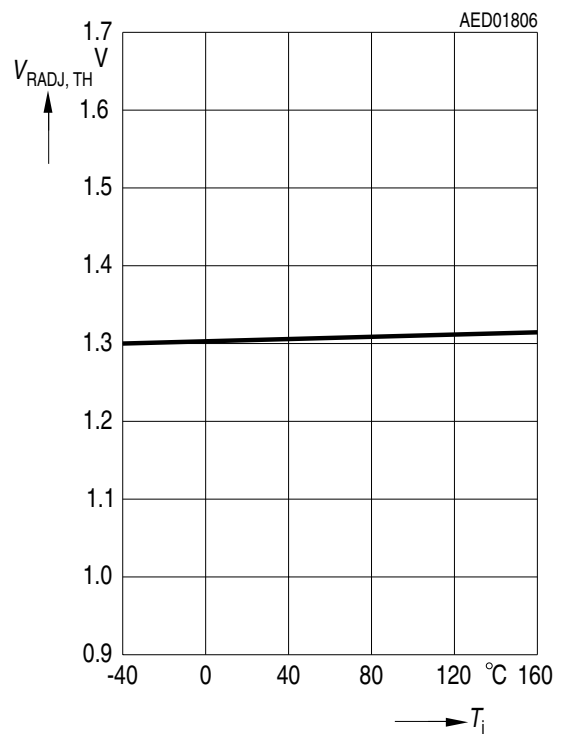
**Switching Voltage  $V_{UD}$  and  $V_{LD}$  versus Temperature  $T_i$**



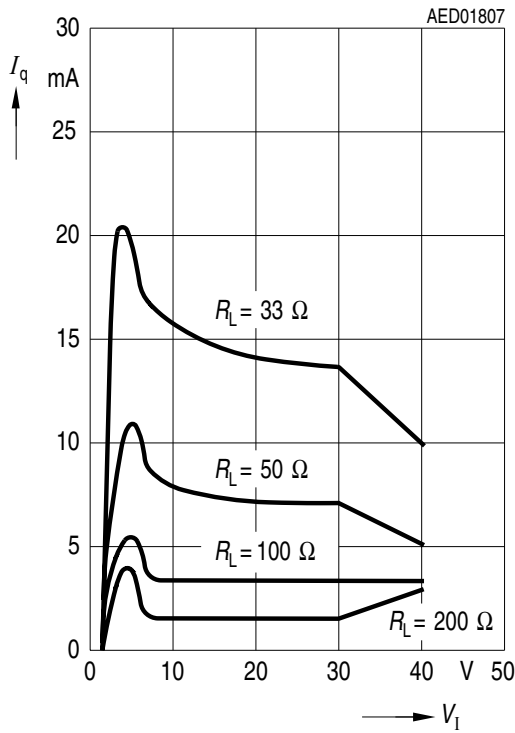
**Drop Voltage  $V_{dr}$  versus Output Current  $I_Q$**



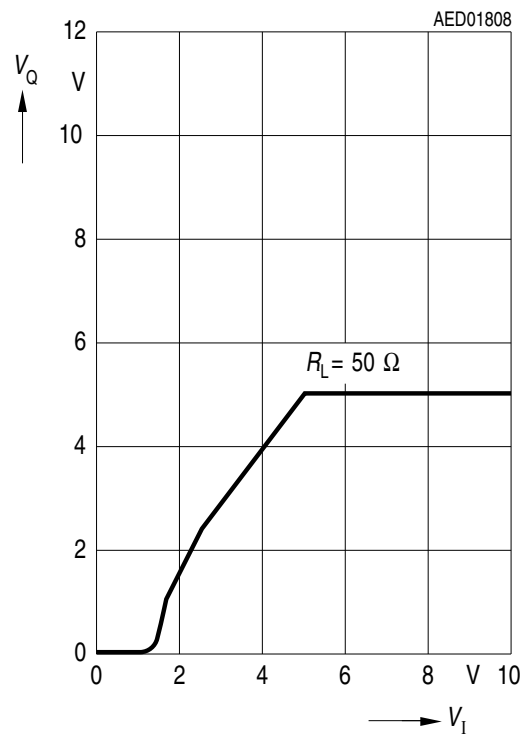
**Reset Adjust Switching Threshold  $V_{RADJ,TH}$  versus Temperature  $T_i$**



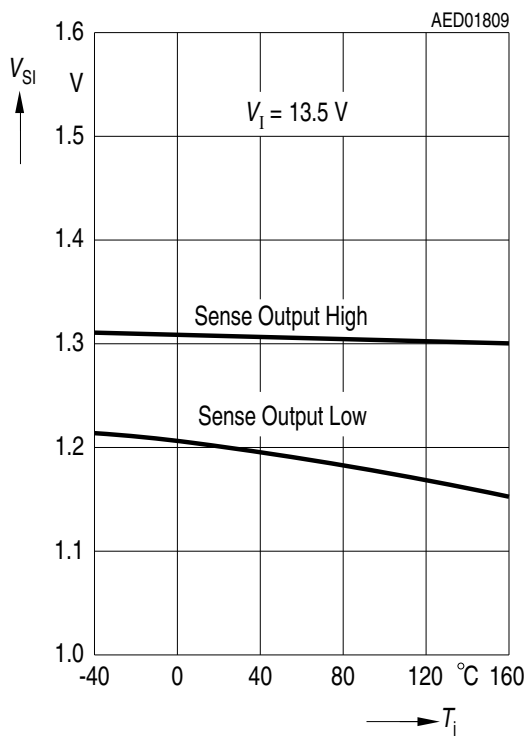
**Current Consumption  $I_Q$  versus Input Voltage  $V_I$**



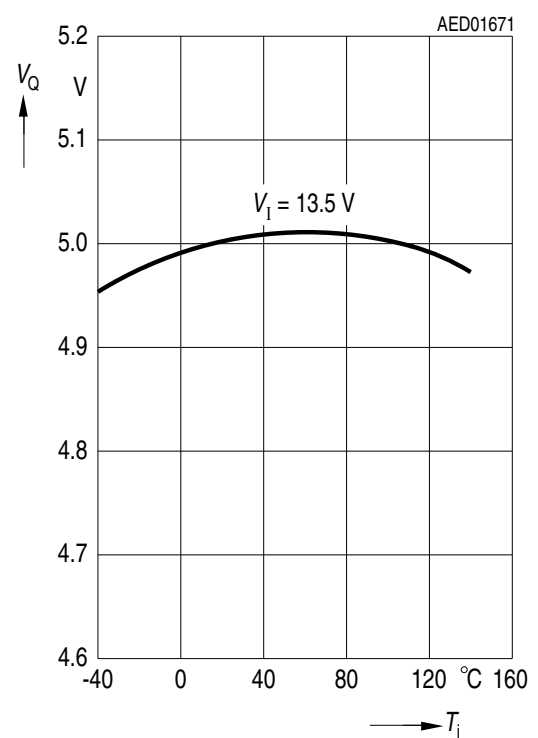
**Output Voltage  $V_Q$  versus Input Voltage  $V_I$**



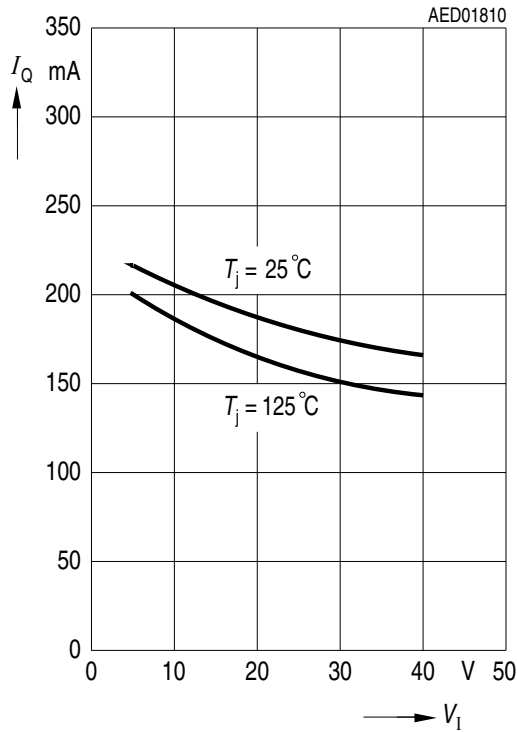
**Sense Threshold  $V_{SI}$  versus Temperature  $T_j$**



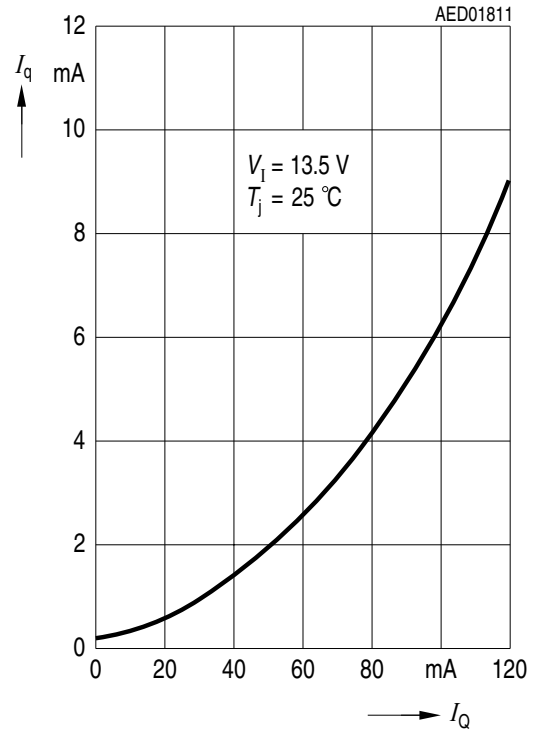
**Output Voltage  $V_Q$  versus Temperature  $T_j$**



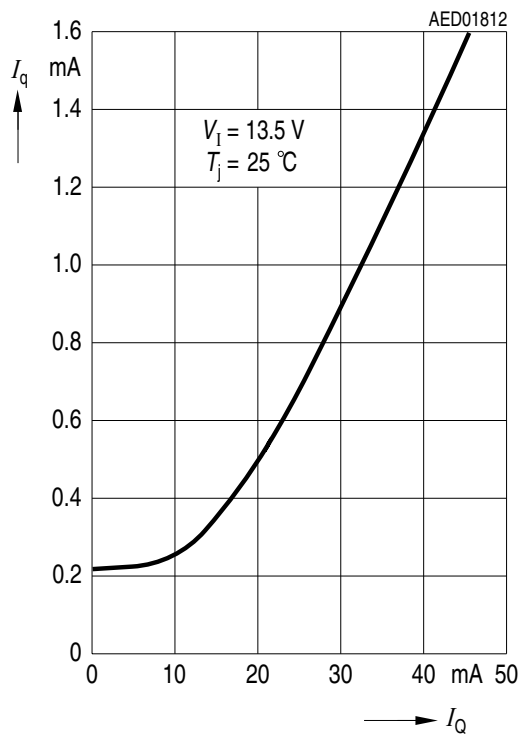
**Output Current  $I_Q$  versus Input Voltage  $V_I$**



**Current Consumption  $I_q$  versus Output Current  $I_Q$**



**Current Consumption  $I_q$  versus Output Current  $I_Q$**



Package Outlines

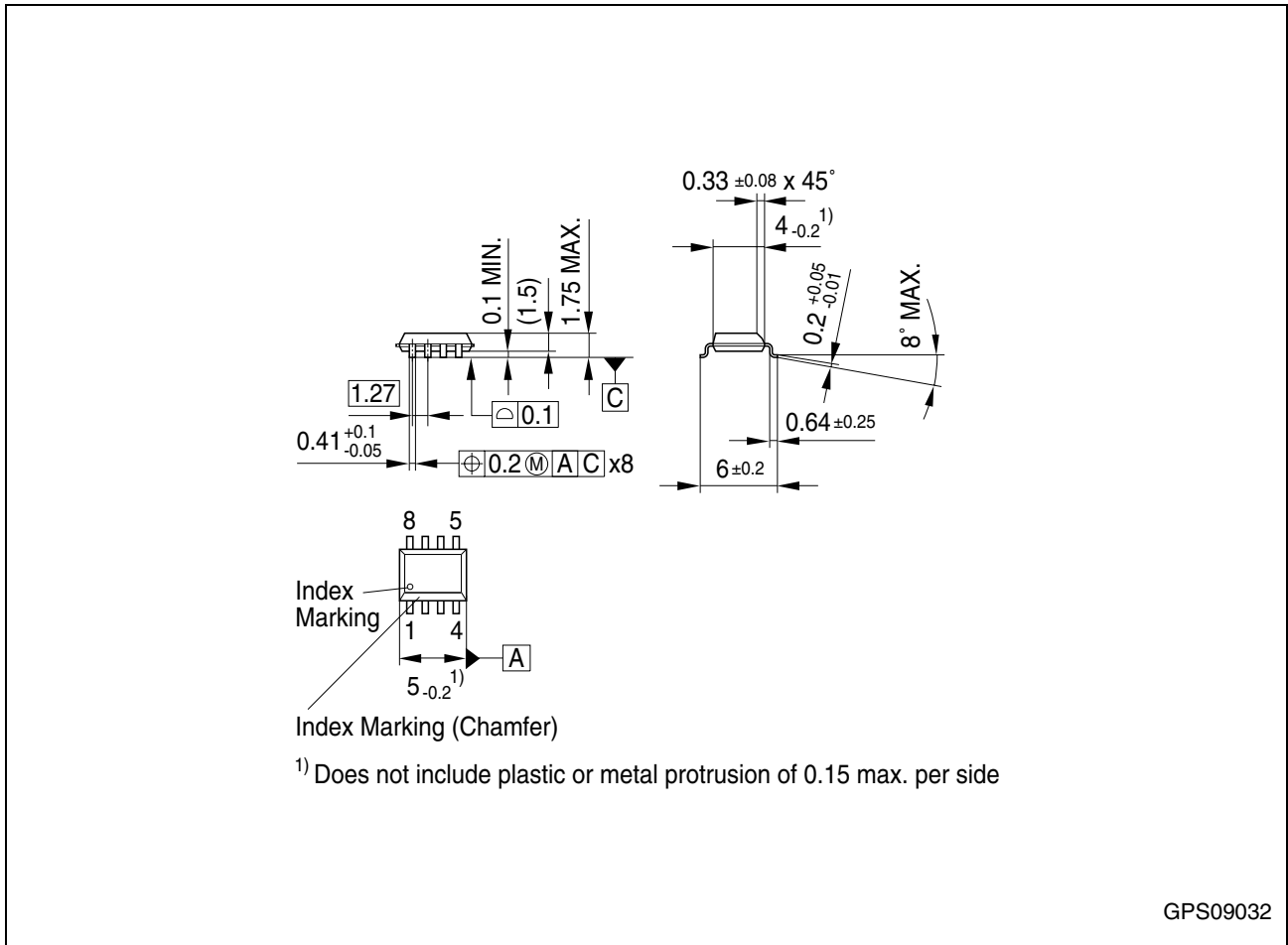
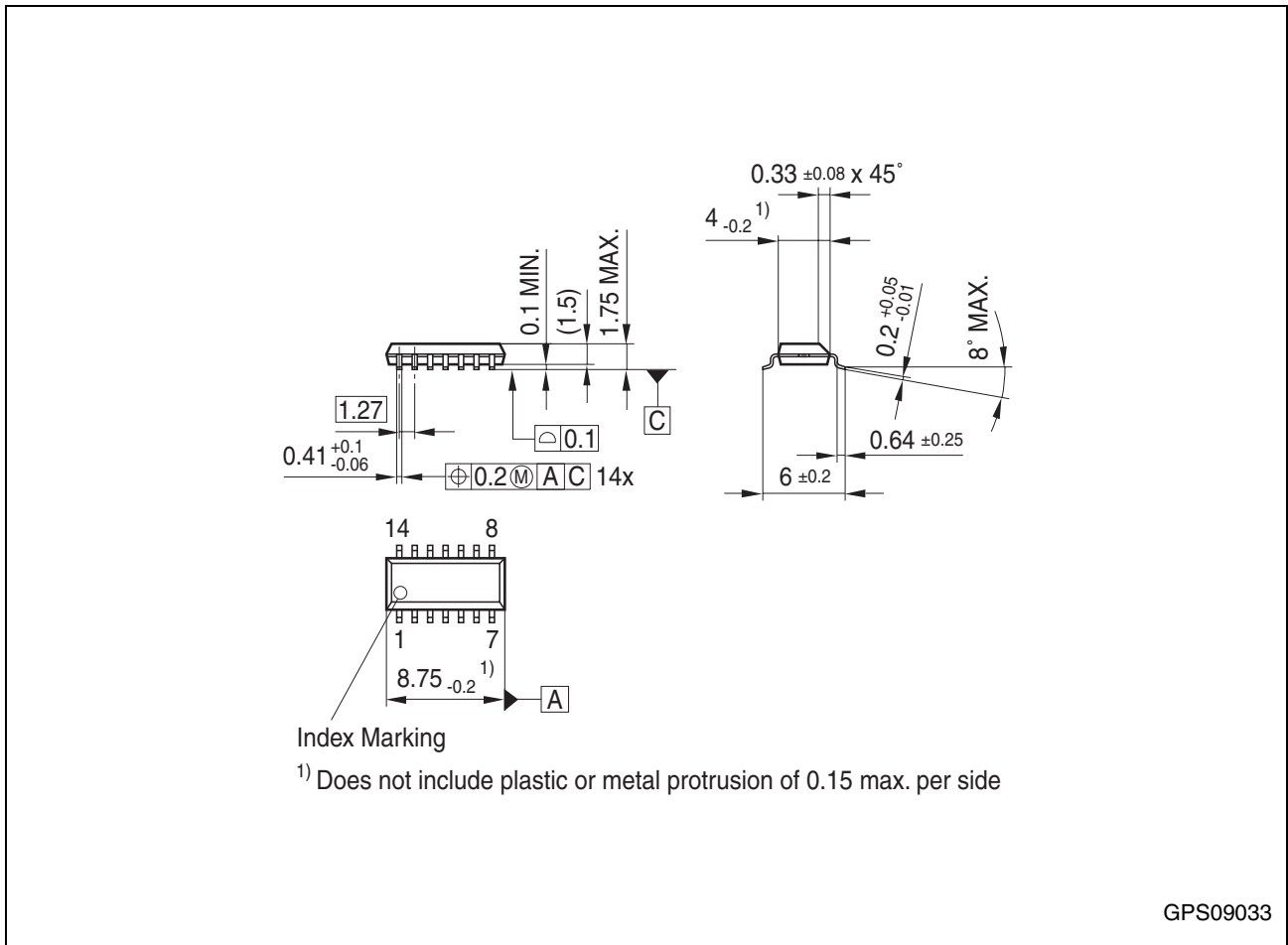


Figure 8 P-DSO-8-3 (Plastic Dual Small Outline)

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SMD = Surface Mounted Device

Dimensions in mm



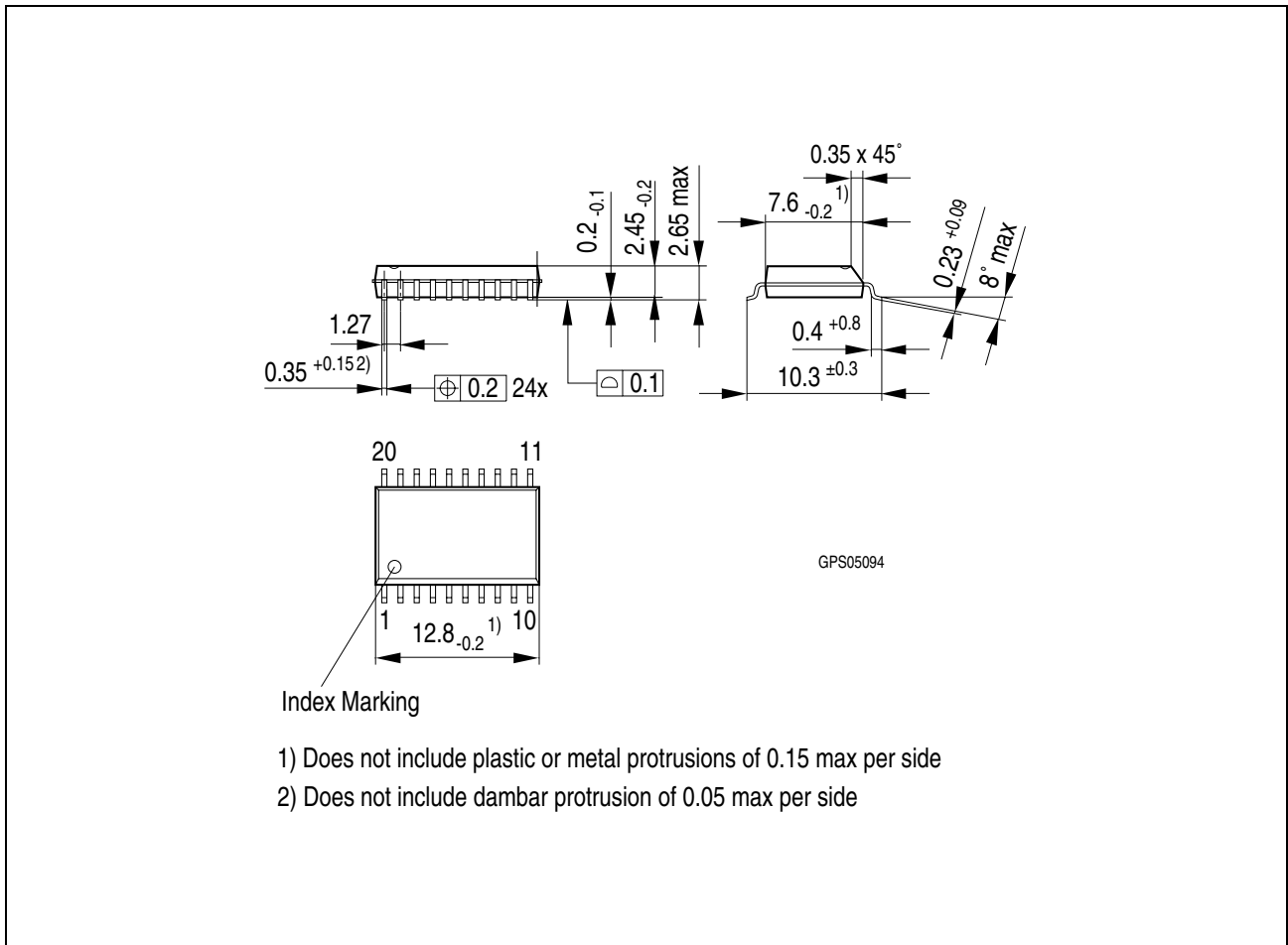
**Figure 9** P-DSO-14-8 (Plastic Dual Small Outline)

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SMD = Surface Mounted Device

Dimensions in mm





**Figure 10 P-DSO-20-17 (Plastic Dual Small Outline)**

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SMD = Surface Mounted Device

Dimensions in mm

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